

Study of Terahertz Emission from MoS₂ Interdigitated Antennas

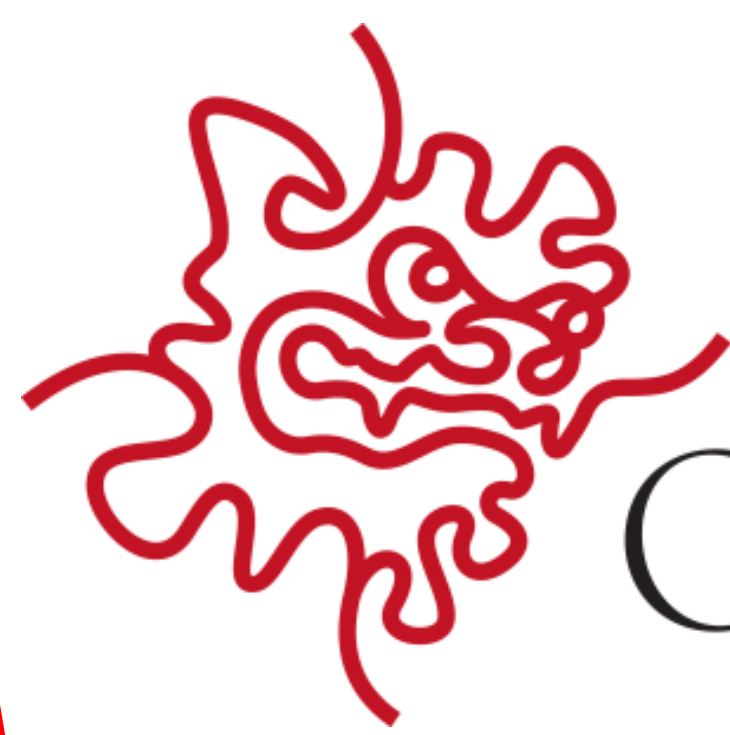
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We study the THz emission properties of interdigitated THz antennas using MoS₂ as the conductive medium. Given the recent discovery of a direct bandgap and the resulting photoconductive properties of monolayer MoS₂, THz emission from these antennas have the potential for technological and commercial improvements over current GaAs antennas. This poster will show the fabrication process of interdigitated antennas using MoS₂, as well as the design and construction of a terahertz time-domain spectrometer to study THz emission. The properties of the THz spectrometer are first characterized using interdigitated GaAs antennas, and current progress in studying the THz emission from the MoS₂ antennas will be discussed.



Purpose: We study the THz emission properties of interdigitated THz antennas using Molybdenum Disulphide(MoS₂) as the conductive medium. With the recent discovery of a direct bandgap and the photoconductive properties of monolayer MoS₂, Terahertz (THz) emission from these antennas have the potential for technological and commercial applications. This poster discusses our current progress in the fabrication process of interdigitated antennas using few- to mono-layer flakes of MoS₂, as well as the design and construction of a terahertz time-domain spectrometer to study THz emission.

Antenna Fabrication

1) Printing the layers of an antenna (see figure 1). The full procedure is listed below:

- 1 cm² silicon/silicon dioxide substrates were cleaned.
 - Acetone bath followed with isopropanol (IPA) rinse.
- Substrates exposed to MoS₂
 - Liquid-phase exfoliated drop cast (See figure 2).
 - Chemical Vapor Deposition (CVD) (See figure 3).
 - One dummy cell- no exposure
- Photoresist spin coated at 1μm
- Maskless Lithography followed with development of the substrates.
- First layer of Ti/Au at 1:10 ratio (Used 6:60 nm coating)
- Lift off: samples submerged in acetone to dissolve remaining photoresist and 'lift off' the gold on those areas.
 - IPA rinse and dried with N₂
- Photoresist applied a second time followed by maskless lithography and development
- SiO₂ deposition via CVD (400-500 nm)
 - Lift off repeated
- Photoresist applied a final time, maskless lithography, and development
- Ti/Au coating (same thicknesses used before)
 - Lift off procedures

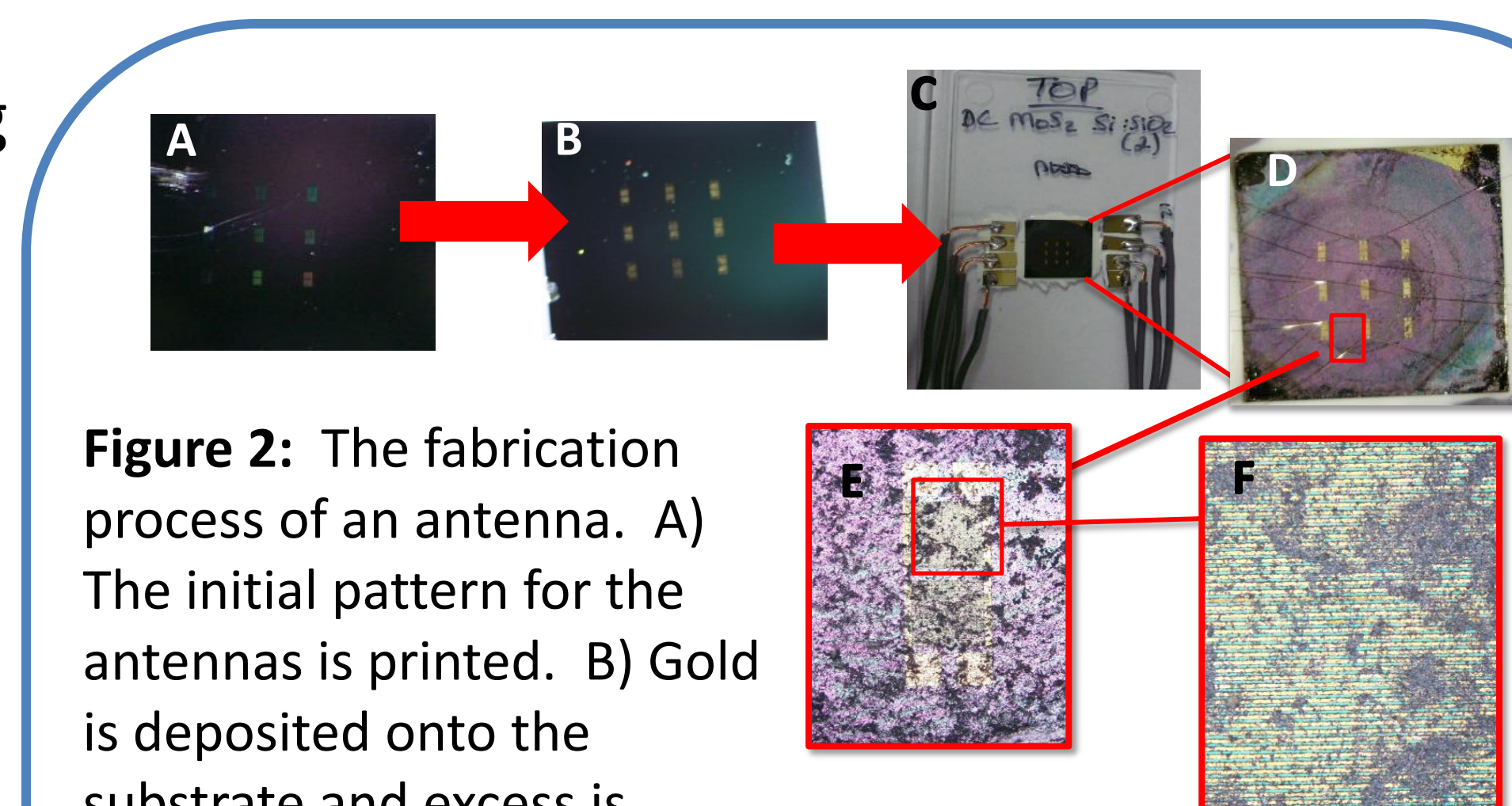
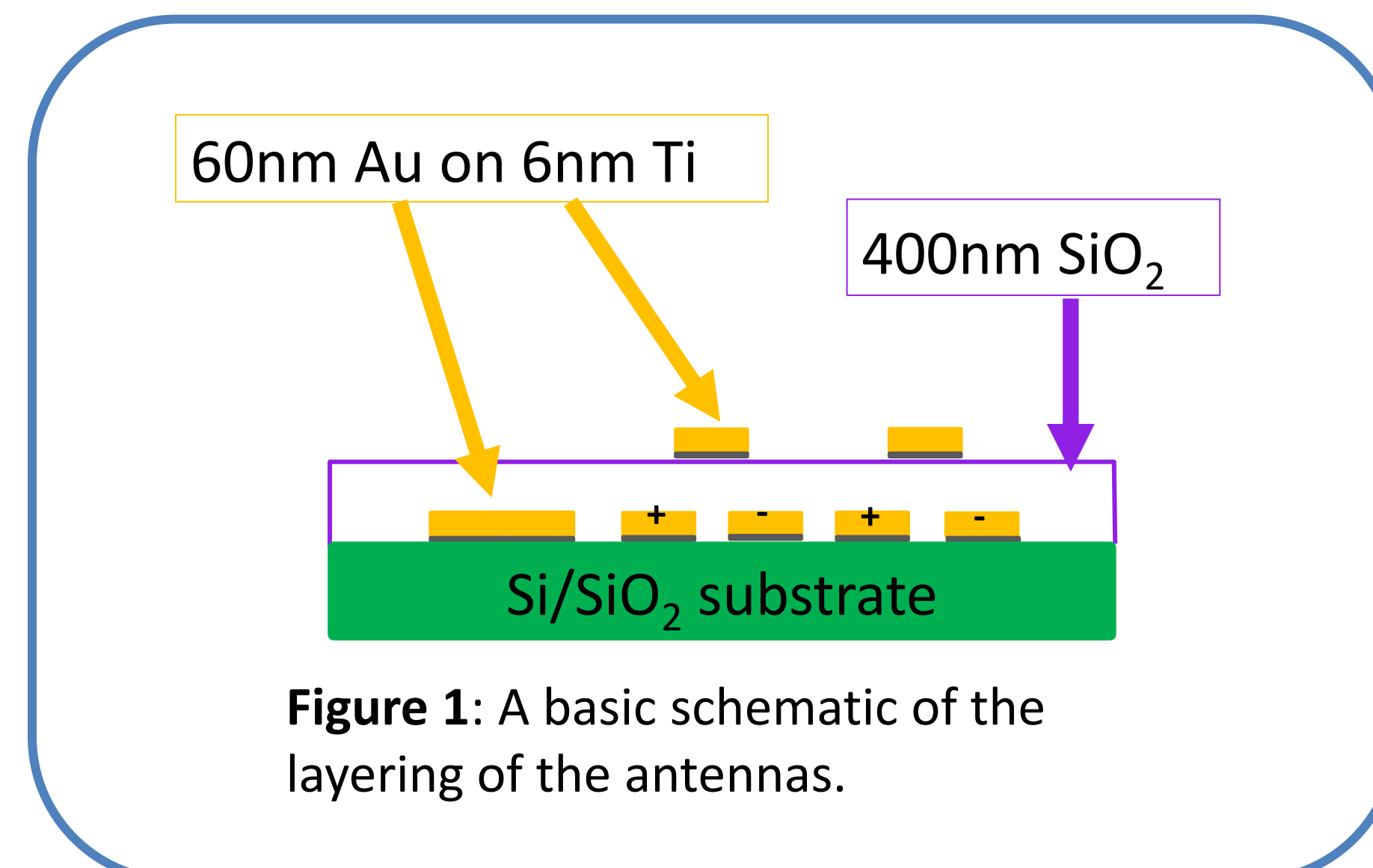


Figure 2: The fabrication process of an antenna. A) The initial pattern for the antennas is printed. B) Gold is deposited onto the substrate and excess is removed. Processes A& B are repeated for a SiO₂ layer and another gold layer. C) The final devices (drop cast MoS₂ sample imaged here) are secured to a base plate and wire bonded to larger contact pads. D) Magnified image of the wire bonded substrate. E) Image of a pair of antennas magnified at 10x. F) Image of fingers of the antenna 50x magnification.

2) Characterization of the printed antennas:

- Probe station used to identify working antennas (a resistance on the order of mega ohms is required to constitute a working device).

3) Finalization of the antennas:

- Entire substrate glued to a base plate with large contact pads
- Wire bonding done between large contact pads and small contact pads on the antennas.
- Contact pads soldered to wires and loaded into spectrometer for testing.

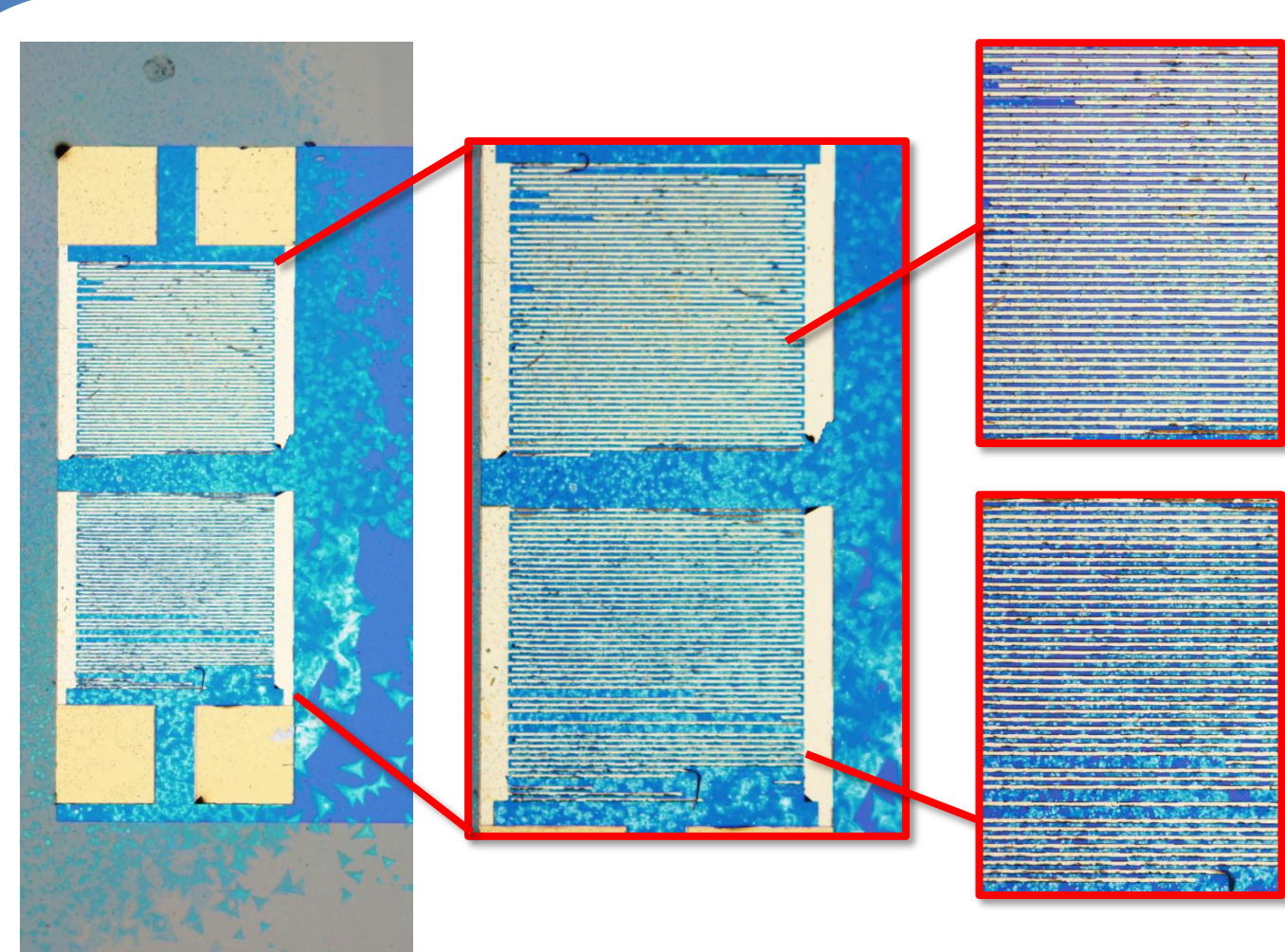


Figure 3: Images of antennas printed on CVD grown MoS₂ at 10x, 20x, and 50x magnification.

Future Work:

The challenges and next steps required to complete the fabrication of a fully functioning MoS₂ Interdigitated Antenna are:

- 1- Determine reason behind samples 'burning' after SiO₂ deposition.
- 2- Compare and optimize the measured photocurrent with that reported in literature.
- 3- Test for and optimize terahertz emission.

Terahertz Detection

In parallel, we designed and built a Terahertz spectrometer to study THz emission (Fig. 3 & 4)

- An 800nm, 45fs beam (from a 4MHz, 650nJ oscillator) is divided into two
 - a generation beam: to photoexcite the antennas
 - a gating beam: to measure emitted THz using a ZnTe crystal
- Two parabolic mirrors collimate and refocus the emitted THz radiation

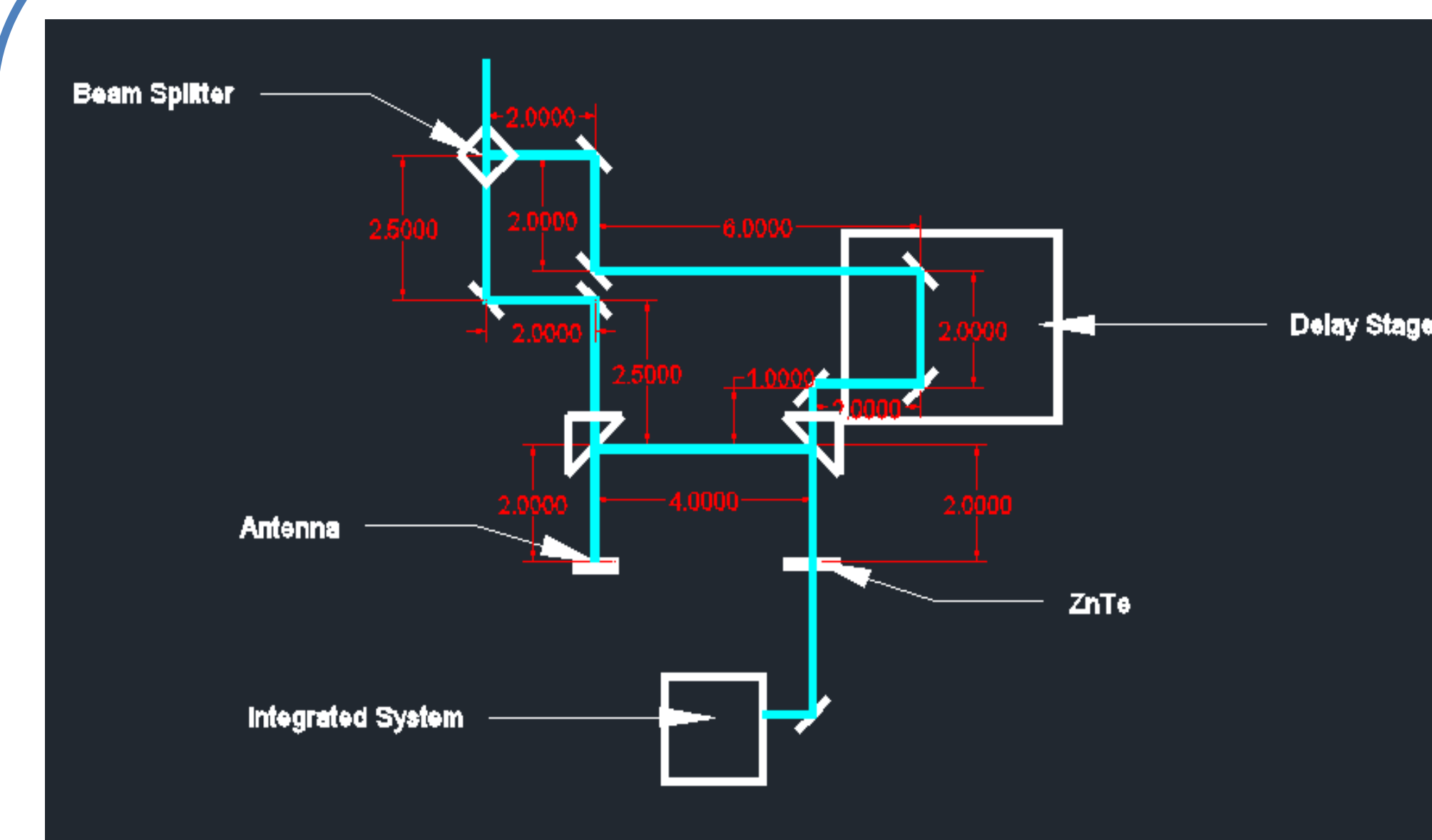


Figure 3: Preliminary drawing for the set-up.

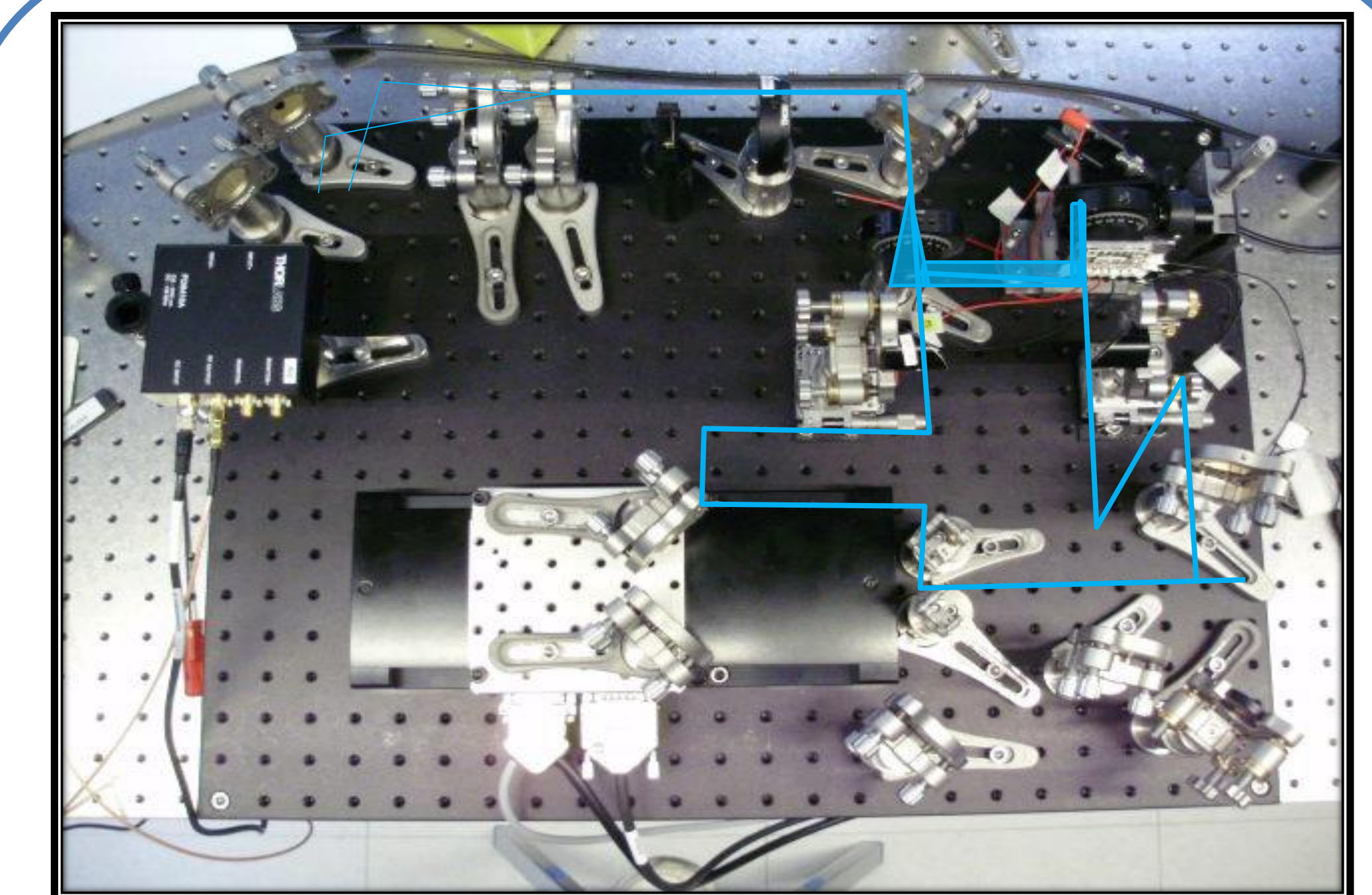


Figure 4: Final set-up: Space limitations resulted in modifications to the preliminary drawing.

Results:

Using a biased GaAs antenna as reference modulated at 10kHz and photoexcitation power of 200mW, the spectrometer was able to detect a few cycle terahertz wave form with a bandwidth of 1.5THz. Further optimization is in progress.

Future Work:

- 1- Improve SNR and detectable bandwidth.
- 2- Build a purge box to eliminate humidity in the system.

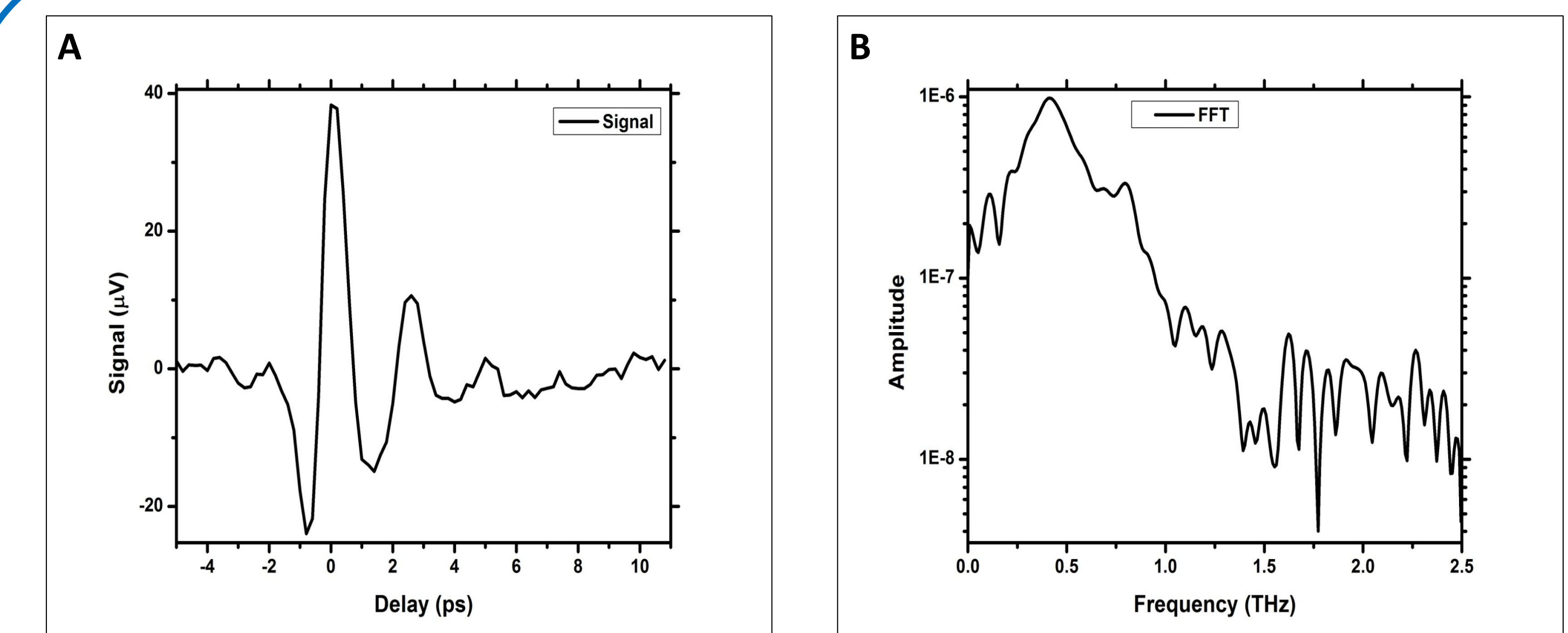


Figure 5: A) Initial waveform without purge B)Fourier transform of the wave form.

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